

Vishay General Semiconductor

Surface Mount PAR® Transient Voltage Suppressors

High Temperature Stability and High Reliability Conditions



Anode	\circ	-0	Cathode

PRIMARY CHARACTERISTICS					
V_{WM}	10 V to 43 V				
V_{BR}	11.1 V to 52.8 V				
P _{PPM} (10 x 1000 μs)	4600 W				
P _{PPM} (10 x 10 000 μs)	3600 W				
P_{D}	6 W				
I _{FSM}	600 A				
T _J max.	175 °C				
Polarity	Unidirectional				
Package	DO-218AC				

FEATURES

 Junction passivation optimized design passivated anisotropic rectifier technology

- T_J = 175 °C capability suitable for high reliability compliant and automotive requirement
- · Available in unidirectional polarity only
- · Low leakage current
- · Low forward voltage drop
- High surge capability
- Meets ISO7637-2 surge specification (varied by test condition)
- Meets MSL level 1, per J-STD-020, LF maximum peak of 245 °C
- AEC-Q101 qualified
 - Automotive ordering code: base P/NHE3
- Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>

TYPICAL APPLICATIONS

Use in sensitive electronics protection against voltage transients induced by inductive load switching and lighting, especially for automotive load dump protection application.

MECHANICAL DATA

Case: DO-218AC

Molding compound meets UL 94 V-0 flammability rating Base P/NHE3 - RoHS-compliant, AEC-Q101 qualified

Terminals: matte tin plated leads, solderable per

J-STD-002 and JESD 22-B102

HE3 suffix meets JESD 201 class 2 whisker test

Polarity: heatsink is anode

MAXIMUM RATINGS (T _C = 25 °C unless otherwise noted)						
PARAMETER	SYMBOL	VALUE	UNIT			
Peak pulse power dissipation	with 10/1000 µs waveform	Б	4600	W		
	with 10/10 000 µs waveform	P _{PPM}	3600			
Power dissipation on infinite heatsink at T _C = 25 °C (fig. 1)		P _D	6.0	W		
Peak pulse current with 10/1000 µs waveform		I _{PPM} ⁽¹⁾	See next table	А		
Peak forward surge current 8.3 ms single half sine-wave		I _{FSM}	600	А		
Operating junction and storage temperature range		T _J , T _{STG}	-55 to +175	°C		

Note

(1) Non-repetitive current pulse at T_A = 25 °C



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ELECTRICAL CHARACTERISTICS (T _C = 25 °C unless otherwise noted)										
DEVICE		REAKDOWN VOLTAGE V _{BR} (V)		TEST CURRENT	STAND-OFF VOLTAGE	MAXIMUM REVERSE LEAKAGE	MAXIMUM REVERSE LEAKAGE	MAX. PEAK PULSE CURRENT	MAXIMUM CLAMPING VOLTAGE	TYPICAL TEMP. COEFFICIENT
TYPE	MIN.	ном.	MAX.	I _T (mA)	V _{WM} (V)	AT V _{WM} Ι _D (μΑ)	AT V _{WM} T _J = 175 °C I _D (μA)	AT 10/1000 µs WAVEFORM (A)	AT I _{PPM} V _C (V)	OF V _{BR} ⁽¹⁾ αT (%/°C)
SM6S10AT	11.1	11.7	12.3	5.0	10.0	15	250	271	17.0	0.069
SM6S11AT	12.2	12.9	13.5	5.0	11.0	10	150	253	18.2	0.072
SM6S12AT	13.3	14.0	14.7	5.0	12.0	10	150	231	19.9	0.074
SM6S13AT	14.4	15.2	15.9	5.0	13.0	10	150	214	21.5	0.076
SM6S14AT	15.6	16.4	17.2	5.0	14.0	10	150	198	23.2	0.078
SM6S15AT	16.7	17.6	18.5	5.0	15.0	10	150	189	24.4	0.080
SM6S16AT	17.8	18.8	19.7	5.0	16.0	10	150	177	26.0	0.081
SM6S17AT	18.9	19.9	20.9	5.0	17.0	10	150	167	27.6	0.082
SM6S18AT	20.0	21.1	22.1	5.0	18.0	10	150	158	29.2	0.083
SM6S20AT	22.2	23.4	24.5	5.0	20.0	10	150	142	32.4	0.085
SM6S22AT	24.4	25.7	26.9	5.0	22.0	10	150	130	35.5	0.086
SM6S24AT	26.7	28.1	29.5	5.0	24.0	10	150	118	38.9	0.087
SM6S26AT	28.9	30.4	31.9	5.0	26.0	10	150	109	42.1	0.088
SM6S28AT	31.1	32.8	34.4	5.0	28.0	10	150	101	45.4	0.089
SM6S30AT	33.3	35.1	36.8	5.0	30.0	10	150	95	48.4	0.090
SM6S33AT	36.7	38.7	40.6	5.0	33.0	10	150	86	53.3	0.091
SM6S36AT	40.0	42.1	44.2	5.0	36.0	10	150	79	58.1	0.091
SM6S40AT	44.4	46.8	49.1	5.0	40.0	10	150	71	64.5	0.092
SM6S43AT	47.8	50.3	52.8	5.0	43.0	10	150	66	69.4	0.093

Notes

⁽¹⁾ To calculate V_{BR} vs. junction temperature, use the following formula: V_{BR} at $T_J = V_{BR}$ at 25 °C x (1 + α T x (T_J - 25))

THERMAL CHARACTERISTICS (T _C = 25 °C unless otherwise noted)					
PARAMETER	SYMBOL	VALUE	UNIT		
Typical thermal resistance, junction to case	$R_{ heta JC}$	0.95	°C/W		

ORDERING INFORMATION (Example)							
PREFERRED P/N	UNIT WEIGHT (g)	PREFERRED PACKAGE CODE	BASE QUANTITY	DELIVERY MODE			
SM6S10ATHE3/I (1)	2.550	I	750	13" diameter plastic tape and reel, anode towards the sprocket hole			

Note

(1) AEC-Q101 qualified

For all types maximum V_F = 1.9 V at I_F = 100 A measured on 8.3 ms single half sine-wave or equivalent square wave, duty cycle = 4 pulses
per minute maximum

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RATINGS AND CHARACTERISTICS CURVES (T_A = 25 °C unless otherwise noted)

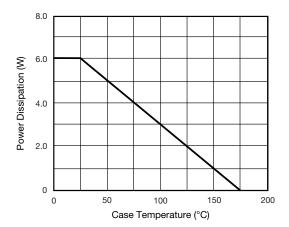


Fig. 1 - Power Derating Curve

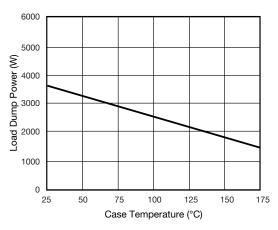


Fig. 2 - Load Dump Power Characteristics (10 ms Exponential Waveform)

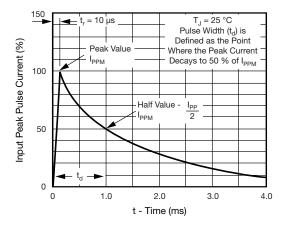


Fig. 3 - Pulse Waveform

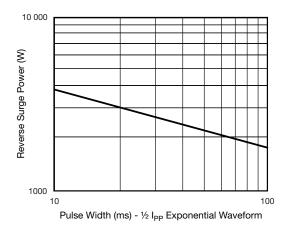


Fig. 4 - Reverse Power Capability

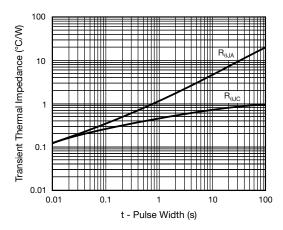


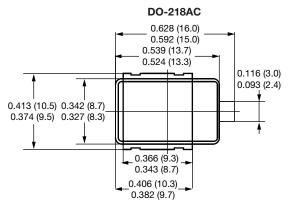
Fig. 5 - Typical Transient Thermal Impedance

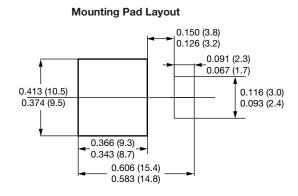


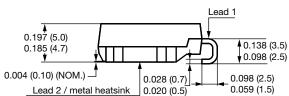
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PACKAGE OUTLINE DIMENSIONS in inches (millimeters)

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